

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.55 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V_{RRM}	120 V			
I _{FSM}	120 A			
V _F at I _F = 10 A	0.64 V			
T _J max.	150 °C			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

ROHS
COMPLIANT
HALOGEN
FREE

- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VF20M120C	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	120	V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20	٨		
	per diode		10	A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	120	А		
Voltage rating of change (rated V _R)		dV/dt	10 000	V/µs		
Isolation voltage from termal to heatsink t = 1 min		V_{AC}	1500	V		
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C		





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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode	I _F = 5 A	- T _A = 25 °C	V _F ⁽¹⁾	0.65	-	V		
	I _F = 10 A			0.82	0.91			
	I _F = 5 A	T _A = 125 °C		0.55	-			
	I _F = 10 A			0.64	0.72			
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	3	-	μA		
		T _A = 125 °C		1.5	-	mA		
	V _D = 120 V	T _A = 25 °C		-	700	μA		
		T _A = 125 °C		4	25	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 20 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VF20M120C	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	5.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	VF20M120C-M3/4W	1.75	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

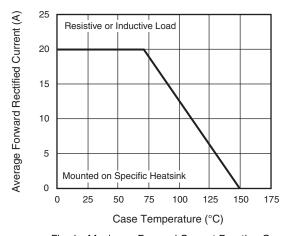


Fig. 1 - Maximum Forward Current Derating Curve

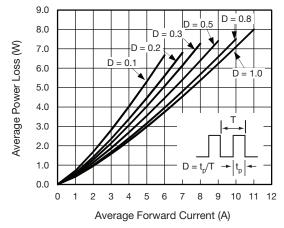


Fig. 2 - Forward Power Loss Characteristics Per Diode



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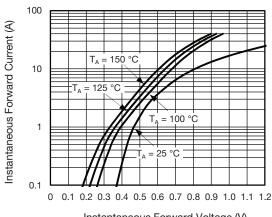
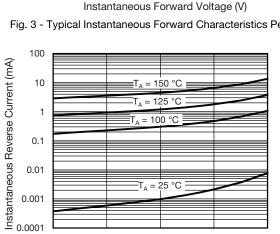


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



Percent of Rated Peak Reverse Voltage (%) Fig. 4 - Typical Reverse Characteristics Per Diode

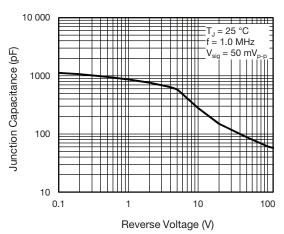


Fig. 5 - Typical Junction Capacitance Per Diode

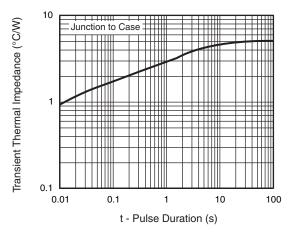


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

100

ITO-220AB 0.190 (4.83) 0.404 (10.26) 0.384 (9.75) 0.170 (4.32) 0.110 (2.79) 0.076 (1.93) REF. 0.100 (2.54) v 7° REF. 0.076 (1.93) REF 45° REF 0.140 (3.56) DIA. 0.135 (3.43) DIA. 0.125 (3.17) DIA. 0.122 (3.08) DIA. 0.671 (17.04) 0.600 (15.24) 7° RÉF 0.651 (16.54) 0.580 (14.73 PIN 0.350 (8.89) 0.330 (8.38) 0.191 (4.85) 0.171 (4.35) 0.560 (14.22) 0.530 (13.46) 0.110 (2.79) 0.100 (2.54) 0.057 (1.45) 0.057 (1.45) 0.045 (1.14) 0.045 (1.14) 0.035 (0.89) 0.025 (0.64) 0.028 (0.71) 0.025 (0.64) 0.015 (0.38) 0.020 (0.51) 0.105 (2.67) 0.205 (5.21) 0.095 (2.41) 0.195 (4.95)



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